# D44H Series (NPN), D45H Series (PNP)

# **Complementary Silicon Power Transistors**

These series of plastic, silicon NPN and PNP power transistors can be used as general purpose power amplification and switching such as output or driver stages in applications such as switching regulators, converters and power amplifiers.

### Features

- Low Collector-Emitter Saturation Voltage
- Fast Switching Speeds
- Complementary Pairs Simplifies Designs
- These Devices are Pb-Free and are RoHS Compliant\*

| Rating  | Symbol                            | Value       | Unit |
|---|-----------------------------------|-------------|------|
| Collector–Emitter Voltage<br>D44H8, D45H8<br>D44H11, D45H11               | V <sub>CEO</sub>                  | 60<br>80    | Vdc  |
| Emitter Base Voltage  | V <sub>EB</sub>                   | 5.0         | Vdc  |
| Collector Current – Continuous  | Ι <sub>C</sub>                    | 10          | Adc  |
| Collector Current – Peak (Note 1)   | I <sub>CM</sub>                   | 20          | Adc  |
| Total Power Dissipation<br>@ $T_C = 25^{\circ}C$<br>@ $T_A = 25^{\circ}C$ | P <sub>D</sub>                    | 70<br>2.0   | W    |
| Operating and Storage Junction<br>Temperature Range                       | T <sub>J</sub> , T <sub>stg</sub> | -55 to +150 | °C   |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected. 1. Pulse Width  $\leq 6.0$  ms, Duty Cycle  $\leq 50\%$ .

### THERMAL CHARACTERISTICS

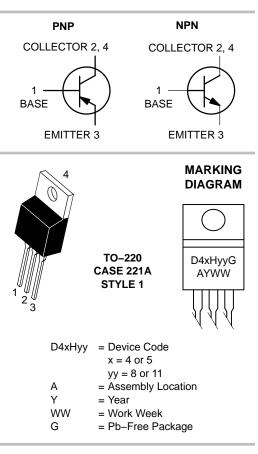
| Characteristic   | Symbol          | Max  | Unit |
|--|-----------------|------|------|
| Thermal Resistance, Junction-to-Case   | $R_{\theta JC}$ | 1.8  | °C/W |
| Thermal Resistance, Junction-to-Ambient  | $R_{\thetaJA}$  | 62.5 | °C/W |
| Maximum Lead Temperature for Soldering<br>Purposes: 1/8" from Case for 5 Seconds | ΤL              | 275  | °C   |



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# 10 AMP COMPLEMENTARY SILICON POWER TRANSISTORS 60, 80 VOLTS



## ORDERING INFORMATION

| Device  | Package             | Shipping      |
|---------|---------------------|---------------|
| D44H8G  | TO–220<br>(Pb–Free) | 50 Units/Rail |
| D44H11G | TO-220<br>(Pb-Free) | 50 Units/Rail |
| D45H8G  | TO-220<br>(Pb-Free) | 50 Units/Rail |
| D45H11G | TO-220<br>(Pb-Free) | 50 Units/Rail |

\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

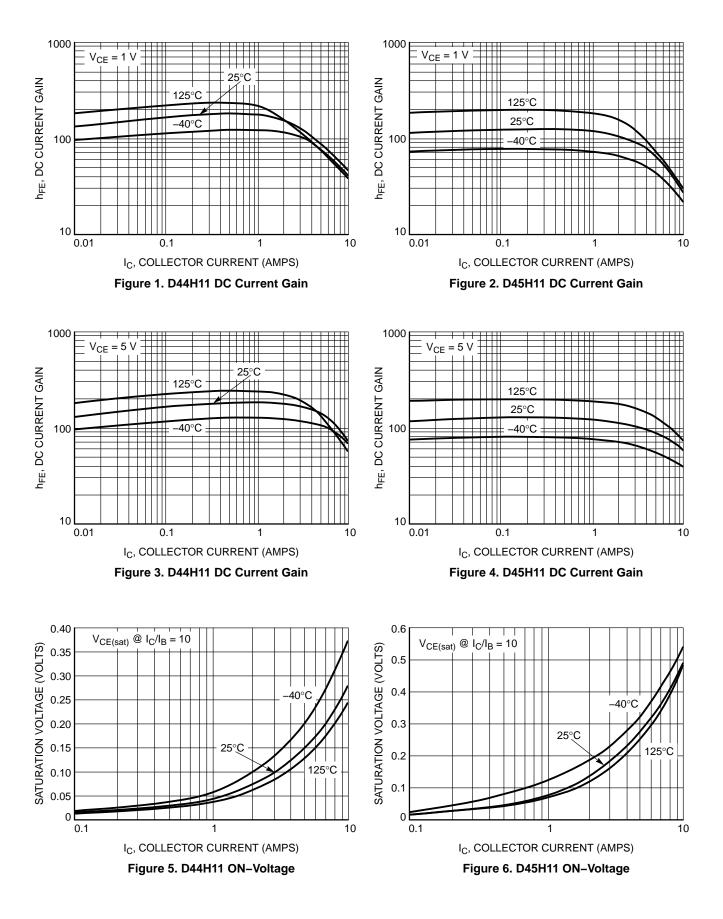
# D44H Series (NPN), D45H Series (PNP)

## **ELECTRICAL CHARACTERISTICS** ( $T_C = 25^{\circ}C$ unless otherwise noted)

| Characteristic  | Symbol                         | Min                             | Тур      | Max        | Unit     |     |
|---|--------------------------------|---------------------------------|----------|------------|----------|-----|
| OFF CHARACTERISTICS   |                                |                                 |          |            | <u> </u> | 4   |
| Collector–Emitter Sustaining Voltage $(I_C = 30 \text{ mAdc}, I_B = 0 \text{ Adc})$                 | D44H8, D45H8<br>D44H11, D45H11 | V <sub>CEO(sus)</sub>           | 60<br>80 |            |          | Vdc |
| Collector Cutoff Current (V <sub>CE</sub> = Rated V <sub>CEO</sub> , V <sub>BE</sub>                | = 0)                           | I <sub>CES</sub>                | _        | -          | 10       | μΑ  |
| Emitter Cutoff Current (V <sub>EB</sub> = 5.0 Vdc)  |                                | I <sub>EBO</sub>                | _        | -          | 10       | μΑ  |
| ON CHARACTERISTICS  |                                |                                 |          |            |          |     |
| DC Current Gain<br>( $V_{CE} = 1.0$ Vdc, $I_C = 2.0$ Adc)<br>( $V_{CE} = 1.0$ Vdc, $I_C = 4.0$ Adc) |                                | h <sub>FE</sub>                 | 60<br>40 |            |          | -   |
| Collector–Emitter Saturation Voltage $(I_C = 8.0 \text{ Adc}, I_B = 0.4 \text{ Adc})$               |                                | V <sub>CE(sat)</sub>            | -        | -          | 1.0      | Vdc |
| Base–Emitter Saturation Voltage $(I_{C} = 8.0 \text{ Adc}, I_{B} = 0.8 \text{ Adc})$                |                                | V <sub>BE(sat)</sub>            | -        | -          | 1.5      | Vdc |
| DYNAMIC CHARACTERISTICS   |                                |                                 |          |            |          |     |
| Collector Capacitance<br>(V <sub>CB</sub> = 10 Vdc, f <sub>test</sub> = 1.0 MHz)                    | D44H Series<br>D45H Series     | C <sub>cb</sub>                 |          | 90<br>160  |          | pF  |
| Gain Bandwidth Product<br>( $I_C = 0.5 \text{ Adc}, V_{CE} = 10 \text{ Vdc}, f = 20 \text{ MHz}$ )  | D44H Series<br>D45H Series     | fT                              |          | 50<br>40   |          | MHz |
| SWITCHING TIMES   |                                |                                 |          |            |          |     |
| Delay and Rise Times<br>(I <sub>C</sub> = 5.0 Adc, I <sub>B1</sub> = 0.5 Adc)                       | D44H Series<br>D45H Series     | t <sub>d</sub> + t <sub>r</sub> |          | 300<br>135 |          | ns  |
| Storage Time<br>( $I_C = 5.0 \text{ Adc}, I_{B1} = I_{B2} = 0.5 \text{ Adc}$ )                      | D44H Series<br>D45H Series     | t <sub>s</sub>                  | -        | 500<br>500 |          | ns  |
| Fall Time<br>(I <sub>C</sub> = 5.0 Adc, I <sub>B1</sub> = 102 = 0.5 Adc)                            | D44H Series<br>D45H Series     | t <sub>f</sub>                  | -        | 140<br>100 | _        | ns  |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

# D44H Series (NPN), D45H Series (PNP)



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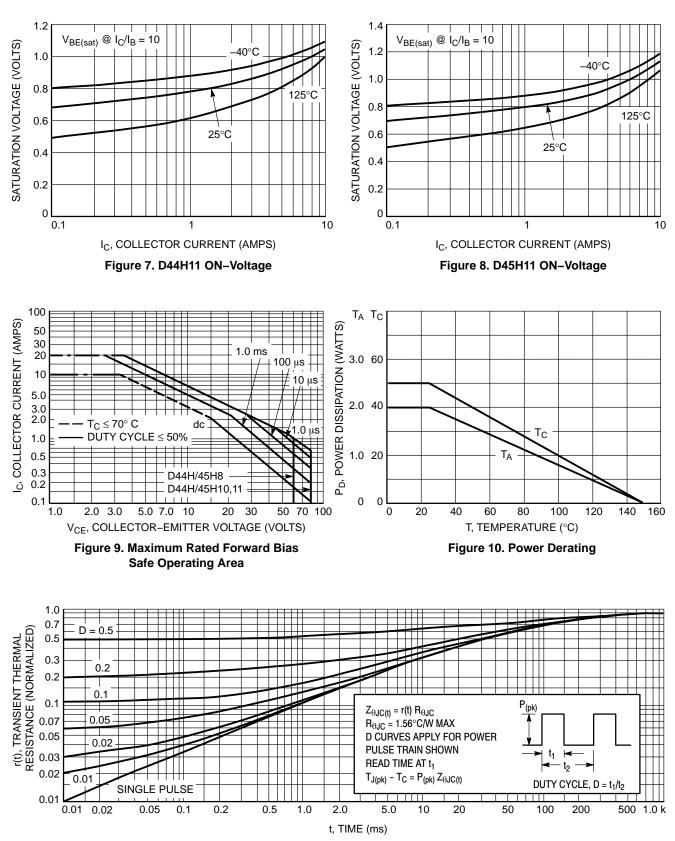
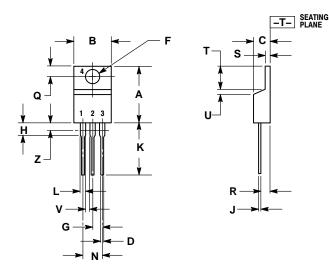


Figure 11. Thermal Response

### PACKAGE DIMENSIONS

TO-220 CASE 221A-09 **ISSUE AH** 



NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH.

3.

DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

|     | INCHES |       | MILLIN | IETERS |
|-----|--------|-------|--------|--------|
| DIM | MIN    | MAX   | MIN    | MAX    |
| Α   | 0.570  | 0.620 | 14.48  | 15.75  |
| В   | 0.380  | 0.415 | 9.66   | 10.53  |
| С   | 0.160  | 0.190 | 4.07   | 4.83   |
| D   | 0.025  | 0.038 | 0.64   | 0.96   |
| F   | 0.142  | 0.161 | 3.61   | 4.09   |
| G   | 0.095  | 0.105 | 2.42   | 2.66   |
| Н   | 0.110  | 0.161 | 2.80   | 4.10   |
| J   | 0.014  | 0.024 | 0.36   | 0.61   |
| Κ   | 0.500  | 0.562 | 12.70  | 14.27  |
| L   | 0.045  | 0.060 | 1.15   | 1.52   |
| Ν   | 0.190  | 0.210 | 4.83   | 5.33   |
| Q   | 0.100  | 0.120 | 2.54   | 3.04   |
| R   | 0.080  | 0.110 | 2.04   | 2.79   |
| S   | 0.045  | 0.055 | 1.15   | 1.39   |
| Т   | 0.235  | 0.255 | 5.97   | 6.47   |
| U   | 0.000  | 0.050 | 0.00   | 1.27   |
| ۷   | 0.045  |       | 1.15   |        |
| Ζ   |        | 0.080 |        | 2.04   |

STYLE 1: BASE PIN 1. 2. COLLECTOR FMITTER 3 COLLECTOR

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